

## Gallium Phosphide as a Piezoelectric Platform for Quantum Optomechanics

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Recent years have seen extraordinary progress in creating quantum states of mechanical oscillators, leading to great interest in potential applications for such systems in both fundamental as well as applied quantum science. One example is the use of these devices as transducers between otherwise disparate quantum systems. In this regard, a promising approach is to build integrated piezoelectric optomechanical devices that are then coupled to microwave circuits. Optical absorption, low quality factors, and other challenges have up to now prevented operation in the quantum regime, however. Here, we design and characterize such a piezoelectric optomechanical device fabricated from gallium phosphide in which a 2.9 GHz mechanical mode is coupled to a high quality factor optical resonator in the telecom band. The large electronic band gap and the resulting low optical absorption of this new material, on par with devices fabricated from silicon, allows us to demonstrate quantum behavior of the structure. This not only opens the way for realizing noise-free quantum transduction between microwaves and optics, but in principle also from various color centers with optical transitions in the near visible to the telecom band.

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The interaction of light and mechanical motion in nano-fabricated resonators provides a flexible interface between telecom photons and long-lived phononic modes. Rapid progress in this field has resulted in the realization of nonclassical states of light and motion at the single-photon and single-phonon level [1–4], demonstrating the suitability of these structures as quantum light-matter interfaces. One particularly interesting application for which these interfaces could provide their unique functionality is the transduction of quantum information between different carriers. To this end, piezoelectric materials are of great interest, as the electromechanical coupling in principle allows for transduction of a quantum state between the microwave and optical frequency domains [5–7]. Additionally, wide-band-gap materials make simultaneous coupling to both visible wavelength light (at which many optically active quantum systems operate) and the low-loss telecom bands in the near-infrared possible [8,9]. One of the main challenges to realize such a quantum transducer is the ability to faithfully exchange excitations between optical and mechanical modes, which requires any stray absorption of light to be minimal in order not to introduce thermal noise.

A particularly interesting class of optomechanical resonators for quantum interfaces is formed from the simultaneous confinement of light and mechanical motion in periodically patterned nanobeams [10]. These devices feature high frequency (few gigahertz) mechanical modes,

such that the resolved sideband regime is accessible with reasonable optical resonator quality factors ( $\gtrsim 2 \times 10^4$ ), while the mechanical mode can be initialized to the quantum ground state by cryogenic cooling. The low mass of the mechanical mode and small optical cavity mode volume allow for strong optomechanical coupling and the monolithic design facilitates on-chip integration with other quantum systems. While optomechanical crystals have been fabricated out of materials such as GaAs [6,7,11], gallium phosphide (GaP) [12,13], LiNbO<sub>3</sub> [14], SiN [15], AlN [5,16], and diamond [17], among others, to date nonclassical optomechanical interaction in such structures has been limited to silicon-based devices.

In this work we realize an optomechanical crystal in GaP featuring high cooperativity interaction between an optical resonance at 1550 nm and a mechanical breathing mode close to 3 GHz. Because of the minimal absorption of GaP at these wavelengths, cooling our device to 7 mK allows us to operate deep in the mechanical quantum ground state with mode occupations of as little as 0.04 phonons. Furthermore, we demonstrate quantum behavior of our device by measuring nonclassical correlations between photons and phonons [1]. Our results validate that the device performs at a similar level to comparable designs in Si [2–4,18], while far surpassing current achievements in GaAs or other piezoelectric materials [7,11]. Owing to the wide electronic band gap and piezoelectric properties of

GaP, the successful operation of our device in this parameter regime opens the door for novel quantum experiments as well as the potential for using such devices for microwave-to-optics conversion. Strong optical  $\chi^{(2)}$  and  $\chi^{(3)}$  nonlinear coefficients [19,20] and the ability to integrate GaP with current silicon technologies [12] make this material a unique platform for quantum experiments and technologies.

Our device consists of an optomechanical crystal evanescently coupled to an optical waveguide, as shown in Fig. 1(a). We fabricate the device from a 200-nm-thick layer of GaP, on a 1  $\mu\text{m}$   $\text{Al}_{0.64}\text{Ga}_{0.36}\text{P}$  sacrificial layer, both epitaxially grown on a GaP substrate. The material features a large refractive index  $n_{\text{GaP}} = 3.05$  at  $\lambda = 1550$  nm [21] as well as a piezoelectric response  $\epsilon_{14} = -0.1$  C m $^{-2}$  [22]. The optomechanical device is designed to exhibit an optical mode in the telecom band ( $\lambda \sim 1560$  nm) as well as a colocalized mechanical mode at  $\omega_m \sim 2\pi \times 2.85$  GHz. The simulated mode profiles are shown in Figs. 1(b) and 1(c). The optomechanical coupling between these modes is realized through the photoelastic effect and the moving boundary conditions due to the shape of the mechanical mode [23]. Simulations of these contributions, with photoelastic coefficients from Ref. [24], predict a single-photon optomechanical coupling strength  $g_0 = 2\pi \times 525$  kHz.

We place our sample inside a dilution refrigerator at a base temperature of  $\sim 7$  mK. Optical access to the device is provided by lensed fiber coupling to the evanescently

coupled reflective waveguide [see Fig. 1(a)]. The initial characterization is performed by scanning a tunable laser across the optical resonance at  $\omega_c = 2\pi \times 194.8$  THz, shown in Fig. 1(b). The mechanical resonance at  $\omega_m = 2\pi \times 2.905$  GHz is obtained by monitoring gigahertz-frequency noise in the reflected light, when stabilizing the laser a few gigahertz blue detuned from the optical resonance, shown in Fig. 1(c). We extract optical and mechanical linewidths of  $\kappa = 2\pi \times 5.14$  GHz (loaded  $Q$  factor of  $3.79 \times 10^4$ ) and  $\gamma_m = 2\pi \times 13.8$  kHz, respectively [cf. Figs. 1(b) and 1(c)]. The optical resonator is overcoupled to the nearby waveguide [see Supplemental Material (SM) for more details [25]], such that we extract an intrinsic linewidth of  $2\pi \times 1.31$  GHz (intrinsic  $Q$  factor of  $1.49 \times 10^5$ ).

While the cryogenic cooling of the device should initialize the mechanical mode in its quantum ground state, previous research [7,11] has indicated that, owing to optical absorption, the measured thermal occupation can be significantly higher [26]. We therefore experimentally determine the absorption-limited mode temperature using sideband thermometry [27,28]. In order to limit the effects of absorption-induced heating, we send 40-ns-long optical pulses to our device, spaced by 160  $\mu\text{s}$ . During this measurement, we stabilize our drive laser to either the blue ( $\omega_l = \omega_c + \omega_m$ ) or red ( $\omega_l = \omega_c - \omega_m$ ) sideband of the optomechanical cavity. The blue (red) pulses realize a two-mode squeezing (state-swap) interaction, which creates (annihilates) an excitation of the mechanical mode and produces a scattered photon on resonance with the optical cavity. We then filter out the reflected pump light and use superconducting nanowire single-photon detectors (SNSPDs) to measure the photons on cavity resonance. The corresponding setup is shown in Fig. 2(a). In the weak excitation limit, the photon rates resulting from the blue ( $\Gamma_b$ ) and red ( $\Gamma_r$ ) sideband drives are proportional to  $p_s(n_{\text{th}} + 1)$  and  $p_s n_{\text{th}}$ , respectively. Here,  $p_s$  is the optical power-dependent scattering probability [1] (see SM for details [25]). This measurement allows us to extract the thermal occupation of the mechanical mode  $n_{\text{th}}$  using the ratio  $n_{\text{th}} = \Gamma_r / (\Gamma_b - \Gamma_r)$ . By performing this measurement at several optical powers, we can assess the thermal mechanical occupation due to quasi-instantaneous heating from the optical drive, which forms the baseline for further experiments. A selection of photon count rates is shown in Fig. 2(b) and the full set of extracted thermal occupations is shown in Fig. 2(c) as a function of  $p_s$ . The measured thermal occupations are as low as  $n_{\text{th}} = 0.041 \pm 0.004$ , a significant improvement over the lowest reported thermal occupations in other III-V based optomechanical devices [7,11]. From the asymmetry measurements, we extract the single-photon optomechanical coupling strength,  $g_0 = 2\pi \times 845 \pm 34$  kHz. We attribute the discrepancy between the simulated and measured values of  $g_0$  to our imperfect knowledge of the photoelastic coefficients of GaP,

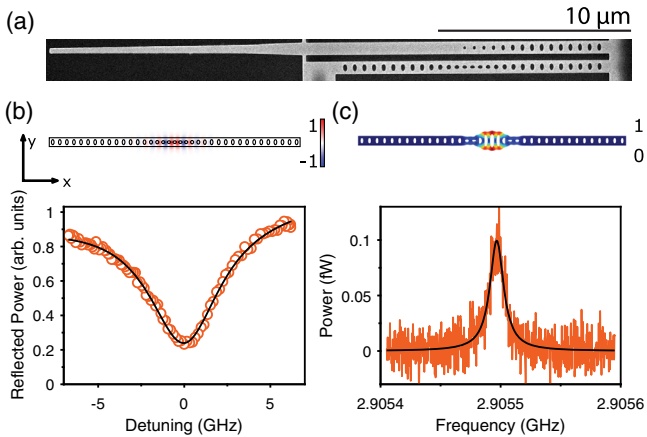


FIG. 1. (a) Scanning electron micrograph of the optomechanical crystal (bottom) with a coupling waveguide (top). (b) Normalized  $E_y$  component of the simulated optical mode (top) and corresponding reflection spectrum of the fabricated device (bottom). The solid black curve is a Lorentzian fit to the data, including a linear offset to account for changing laser power. The overcoupled linewidth of the optical resonance is  $\kappa = 2\pi \times 5.14$  GHz. (c) Normalized displacement of the simulated mechanical mode (top) and power spectral density of the mode at  $\sim 7$  mK (bottom). The solid black curve is a Lorentzian fit to the data. The linewidth of the resonance is  $\gamma_m = 2\pi \times 13.8$  kHz.

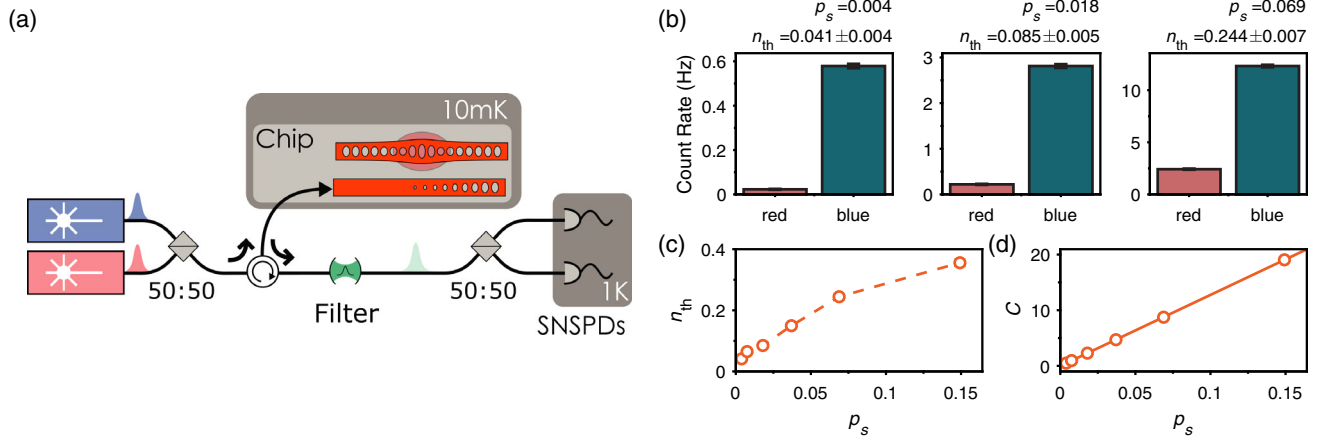


FIG. 2. Device characterization at millikelvin temperatures. (a) Schematic of the measurement setup. We excite or read out our device using a laser on either the red or blue sideband, resulting in cavity-resonant scattered photons. We then filter out the residual pump light and detect the scattered photons on single-photon detectors (SNSPDs). (b) Sideband thermometry measurements taken at varying optical powers (corresponding to different scattering probabilities). The bars represent integrated count rates over the duration of the pulse and the error bars correspond to 1 standard deviation. (c) Extracted thermal occupations from the sideband thermometry measurement. In this panel, the error bars are smaller than the corresponding data points. (d) Extracted values of the cooperativity  $C$  as a function of the scattering probability. The line is a linear fit to the data.

as well as small fabrication-related differences between the designed and actual devices. The power-dependent optomechanical cooperativity,  $C \equiv 4g^2/\kappa\gamma_m$ , with  $g = \sqrt{n_c}g_0$ , and  $n_c$  being the intracavity photon number, is shown in Fig. 2(d). Operating at the highest cooperativities comes at the cost of a raised thermal occupation. However, cooperativities  $C \gg 1$  are achievable while remaining well below  $n_{th} = 1$ . In particular,  $C$  exceeds 1 for a low occupation of  $n_{th} < 0.1$ , an important benchmark for the conversion of quantum states [8].

The parameter regime in which our device operates is similar to recent demonstrations of nonclassical behavior in silicon optomechanical resonators [1–4]. In these optomechanical devices delayed heating of the mechanical mode is a major challenge for quantum experiments [7]. In order to study the presence of similar effects in our current system, we investigate the heating dynamics by sending two consecutive red-detuned pulses to the device. The first pulse provides a source of heating to the thermalized device. The second pulse then converts any thermal phonons at an elevated occupation into photons, resulting in an increased scattering rate ( $\Gamma_r \propto n_{th}$ ). By varying the delay between the two pulses, we can access the time dynamics of the heating process. The measured mode occupations are shown in Fig. 3(a) for three different scattering probabilities. To gain insight into the heating dynamics, the occupations are fitted with a phenomenological two-exponential function [ $n_{th}(\tau) = Ae^{-\tau/\tau_{decay}}(1 - e^{-\tau/\tau_{rise}}) + n_{th,i}$ ]. We extract the characteristic decay constant  $\tau_{decay}$  for the mechanical mode to be  $22 \pm 1 \mu\text{s}$ , in reasonable agreement with the  $Q$  factor extracted from the linewidth of the mechanical mode shown in Fig. 1(c). For these scattering

probabilities, we recover a heating time for the mode  $\tau_{rise}$ , between 150 and 180 ns.

In order to investigate the suitability of GaP as a piezoelectric material platform for quantum optomechanics, we use a pulsing scheme from the Duan-Lukin-Cirac-Zoller (DLCZ) protocol [1,29,30]. It consists of a weak blue-detuned pulse, which excites the mechanical mode with a small probability and returns a scattered photon on resonance with the cavity. A subsequent red-detuned pulse swaps the state of the mechanical mode onto the light field and again produces a cavity-resonant scattered photon. Just as before, both the excitation and readout pulse are 40 ns long. Based on the characteristic heating time  $\tau_{rise}$ , we choose the time delay between our excitation and readout pulses to be 150 ns. As such, we read out the state of the mechanical mode before the delayed heating of the mode adds excess thermal population. Given the small probability of exciting the device, detection of a scattered photon from the weak blue-detuned pulse heralds the creation of a nonclassical mechanical excitation of the resonator, consisting predominantly of a single phonon [2]. The correlation of the projection photon and the remaining phonon (accessed through the red-detuned state-swap pulse) can then be determined through the statistics of the detected photons during many repetitions of the sequence. We operate at scattering probabilities for the write and read pulses of  $p_{s,write} \sim 0.06\%$  (corresponding to 25 nW peak power) and  $p_{s,read} \sim 2\%$  (750 nW), respectively, to limit the parasitic heating, and set the repetition rate to be 25 kHz, such that the mechanical mode can fully rethermalize between each sequence. More details on the experimental parameters can be found in the SM [25].

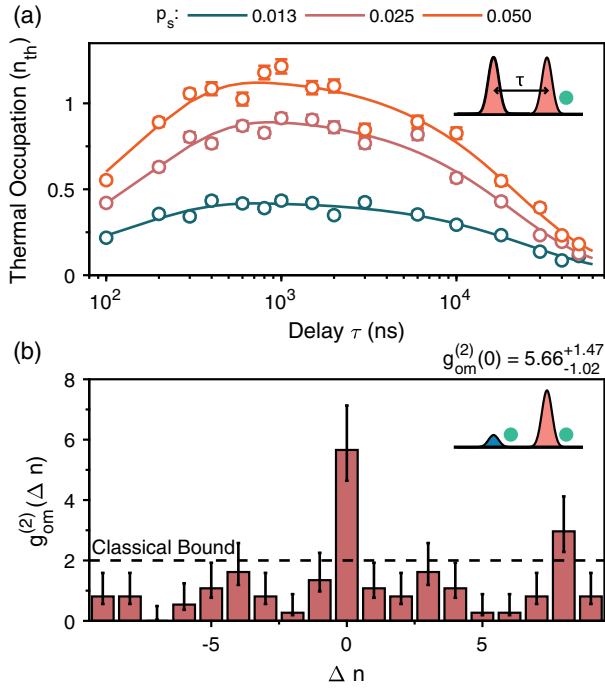


FIG. 3. (a) Heating dynamics of a GaP optomechanical crystal. The data points display the measured occupation of the mechanical mode following an initial red-detuned state-swap pulse, which results in scattering probabilities of 0.013, 0.025, and 0.050. The occupation is inferred from the count rate of a second red-detuned pulse, delayed by time  $\tau$ , as displayed in the inset schematic. The solid curves are phenomenological two-exponential fit to the data, accounting for the delayed onset of thermal excitation and the relaxation time of the mechanical mode. (b) Correlations between state-projecting and state readout photons. The displayed two-photon correlations are calculated by normalizing to the single-photon rates during the blue-detuned (red-detuned) write (state-swap) pulse. The error bars represent 68% confidence intervals.

We analyze the second order correlation  $g_{om}^{(2)}(\Delta n) = P(W \cap R, \Delta n) / [P(W) \times P(R)]$  between detector clicks originating from write ( $W$ ) and read ( $R$ ) pulses from the same ( $\Delta n = 0$ ) or different ( $\Delta n \neq 0$ ) pulse sequences. Here,  $P(W \cap R, \Delta n)$  is the probability of detecting a read photon  $\Delta n$  sequences after a write photon, while  $P(W)$  and  $P(R)$  are the independent detection probabilities of write and read photons. The measured correlation values are displayed in Fig. 3(b). We observe a correlation of  $g_{om}^{(2)} = 5.66^{+1.47}_{-1.02}$  for read and write pulses from the same sequence, and confirm that detection events from different sequences are on average uncorrelated. The uncertainty in our measured correlation value is a 68% confidence interval determined from the likelihood function of rare two-photon coincident events occurring. The high levels of bunching are a clear signature of nonclassical phonon-photon correlations in this system. The correlations we measure here are limited by three sources—the presence of residual incoherent heating in the device from both the write and read

pulses, dark counts in the SNSPDs (0.08 Hz,  $\sim 1/5$  of the write pulse clicks), which are important during the low-probability write pulse, and the imperfect filtering of the drive laser in the detection setup. In order to limit the effect of readout-induced heating and detector dark counts, we consider events occurring in the first 50% of the read pulse, and the central 50 ns of the write pulse, respectively. Small improvements to our optomechanical device and setup will hence allow us to realize more complex single-phonon experiments [2,3].

Based on the optomechanical performance shown in this Letter and the piezoelectric properties of GaP [22], it is pertinent to consider how the device presented here could be adapted for the conversion of quantum states between the microwave and optical domains. This could be achieved by supplementing the nanobeam with a mechanically coupled, resonant piezoelectric actuator [31]. Faithful conversion of a quantum state requires that less than one photon of noise is added throughout such a conversion process. At the same time, efficient conversion requires that the cooperativity of the electromechanical interface must be much greater than 1 and closely matched to the optomechanical cooperativity [8]. As a result of the low optical absorption in GaP observed in our measurements, for an optomechanical cooperativity above 10 [see Figs. 2(c) and 2(d)], a matched electromechanical interface could result in an added noise figure of only 0.02 photons owing to incoherent heating of the device and imperfect sideband resolution [32].

Maintaining a large optomechanical coupling strength requires for the piezoelectric resonator to have a similar mass to the 280 fg mechanical mode studied here. Considering the piezoelectric tensor of GaP and the alignment of the nanobeam to the [110] crystal orientation, the appropriate breathing mode could then be actuated through a vertical electric field. A generic resonator of matched mass and frequency can be formed by designing a 950-nm-wide and 580-nm-long beam between superconducting electrodes in a parallel-plate capacitor configuration [5] (see SM [25]). The resulting interface is expected to convert electrical and mechanical energy with a coupling coefficient  $k_{eff}^2 \approx 0.017\%$ . Assuming a mechanical loss rate equal to our nanobeam, and taking pessimistic values for on-chip parasitic capacitance of  $\sim 100$  fF, an electromechanical cooperativity of 20 could be achieved by the addition of a microwave resonator with a  $Q$  factor of as little as  $\sim 150$ . While further investigations of microwave losses in GaP are required, the devices presented here, together with the recently developed GaP-on-silicon platform [20], offer robust materials systems for incorporation of low-loss coplanar microwave circuitry.

We have demonstrated nonclassical behavior of an optomechanical crystal fabricated from gallium phosphide. Our device can be operated deep in the quantum ground state with significantly reduced heating compared to similar

devices fabricated from GaAs and other piezoelectric materials. GaP combines several unique properties, such as a large electronic band gap, high refractive index, and a significant piezoelectric response, making it extremely well suited for many novel applications for optomechanical quantum systems. Combined with the piezoelectric properties of GaP, our demonstration of nonclassical optomechanical interaction will enable microwave-to-optics converters to operate in a previously unreachable regime. In addition, the large band gap could allow for coupling of photons to quantum systems which natively operate in the visible spectrum. Our system can further be used for nonlinear optics experiments [19,33] owing to the strong optical  $\chi^{(2)}$  and  $\chi^{(3)}$  nonlinearities and the large index contrast between the suspended device and vacuum, potentially even allowing us to increase the optomechanical coupling rate into the strong-coupling regime [34].

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